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[PAM8902KER-P](#)

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30-V_{PP} MONO CLASS-D AUDIO AMPLIFIER FOR PIEZO/CERAMIC SPEAKERS

Description

The PAM8902 is a mono, Class-D audio amplifier with integrated boost converter designed for piezo and ceramic speakers. The PAM8902 is capable of driving a ceramic/piezo speaker with 30V_{PP}(10.6V_{rms}) from a 3.6V power supply. The PAM8902's Boost converter operates at a fixed frequency of 1.5MHz, and provides a 17.5V supply with a minimum number of external components. PAM8902 features an integrated audio low pass filter that rejects high frequency noise thus improving audio fidelity. And three gain modes of 18dB, 22dB and 26dB for ease of use. PAM8902 also provides thermal, short, under- and over-voltage protection.

The PAM8902 is available in a 16-ball 1.95mm x 1.95mm CSP package and 16-pin QFN4x4 package.

Features

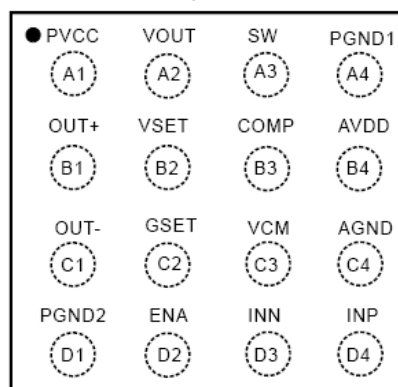
- Supply Voltage Range From 2.5V to 5.5V
- 30 V_{PP} Output Load Voltage From a 2.5V Supply
- Integrated Boost Converter Generates 17.5V Supply
- Programmable Soft-Start
- Small Boost Converter Inductor
- Selectable Gain of 18dB, 22dB, and 26dB
- Selectable Boost Output Voltage of 8V, 12V and 17.5V
- Low Shutdown Current: < 1µA
- Built-in Thermal, OCP, OVP, Short Protection
- Available in Space Saving Packages:
 - 16-ball 1.95mmx1.95mm CSP Package
 - 16-pin QFN4x4 Package

Applications

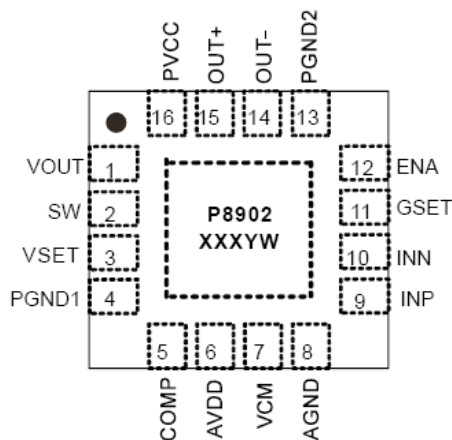
- Wireless or Cellular Handsets
- Portable DVD Player
- Personal Digital Assistants (PDAs)
- Electronic Dictionaries
- Digital Still Cameras

Pin Assignments

16 Ball CSP
Top View

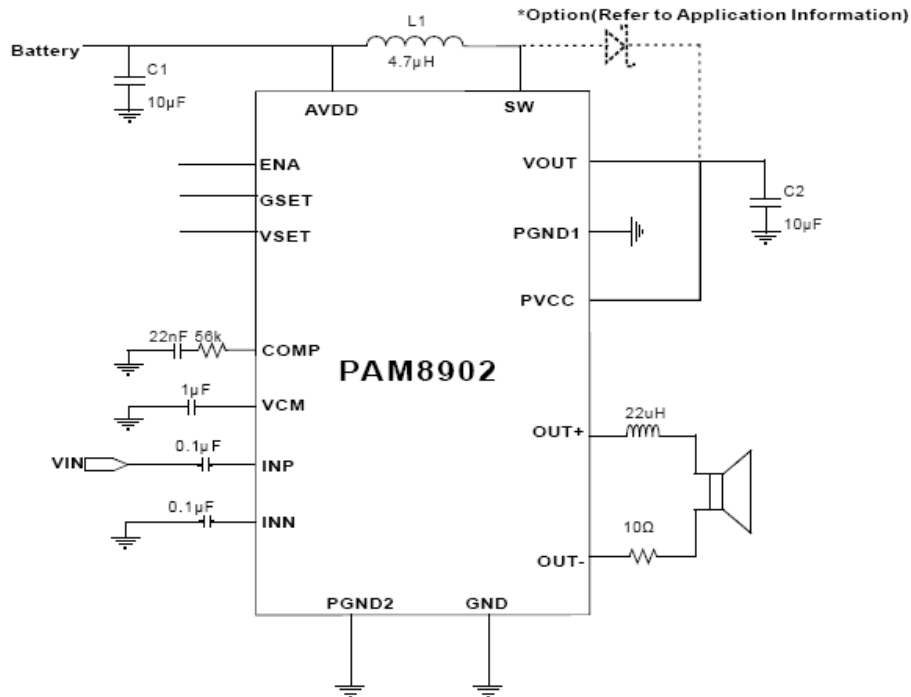


Top View
QFN 4X4 16L



● : Pin 1 Indicator

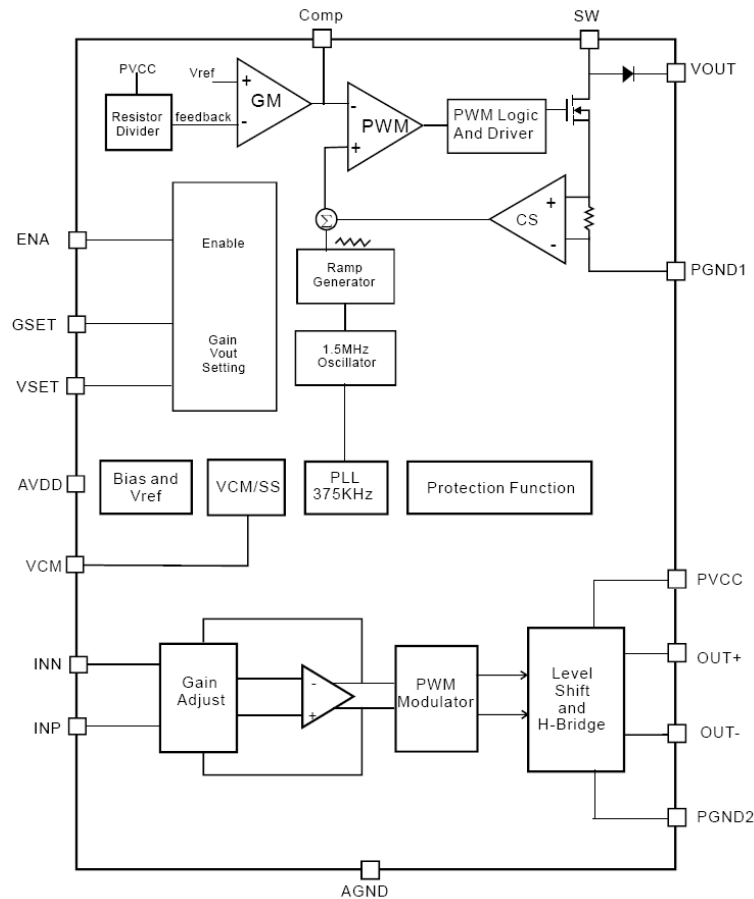
Typical Applications Circuit



Pin Descriptions

| Pin Name | Bump (CSP) | Pin Number QFN4x4 | Function |
|----------|------------|-------------------|--|
| PVCC | A1 | 16 | Audio Amplifier Power Supply |
| VOUT | A2 | 1 | Boost Converter Output |
| SW | A3 | 2 | Boost Converter Switching Node |
| PGND1 | A4 | 4 | Boost Converter Power Ground |
| OUT+ | B1 | 15 | Positive Differential Audio Output |
| VSET | B2 | 3 | Boost Converter Output Voltage Setting(8V,12V,17.5V) |
| COMP | B3 | 5 | Boost Converter Compensation |
| AVDD | B4 | 6 | Power Supply |
| OUT- | C1 | 14 | Negative Differential Audio Output |
| GSET | C2 | 11 | Amplifier Gain Setting (18dB , 22dB , 26dB) |
| VCM | C3 | 7 | Common Mode Bypass Cap |
| AGND | C4 | 8 | Analog Ground |
| PGND2 | D1 | 13 | ClassD Power Ground |
| ENA | D2 | 12 | Whole Chip Enable |
| INN | D3 | 10 | Negative Differential Audio Input |
| INP | D4 | 9 | Positive Differential Audio Input |

Functional Block Diagram



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

These are stress ratings only and functional operation is not implied. Exposure to absolute maximum ratings for prolonged time periods may affect device reliability. All voltages are with respect to ground.

| Parameter | Rating | Unit |
|------------------------------|------------------------------|------|
| Supply Voltage | 6.0 | V |
| Input Voltage | -0.3 to V _{DD} +0.3 | |
| Maximum Junction Temperature | +150 | °C |
| Storage Temperature | -65 to +150 | |
| Soldering Temperature | 350, 10sec | |

Recommended Operating Conditions (@T_A = +25°C, unless otherwise specified.)

| Parameter | Rating | Unit |
|----------------------------|-------------|------|
| Supply Voltage Range | 2.5 to 5.5 | V |
| Ambient Temperature Range | -40 to +85 | °C |
| Junction Temperature Range | -40 to +125 | °C |

Thermal Information

| Parameter | Package | Symbol | Max | Unit |
|--|-----------|---------------|-----|------|
| Thermal Resistance (Junction to Ambient) | CSP | θ_{JA} | 90 | °C/W |
| | QFN4x4-16 | | 52 | |
| Thermal Resistance (Junction to Case) | CSP | θ_{JC} | 75 | |
| | QFN4x4-16 | | 30 | |

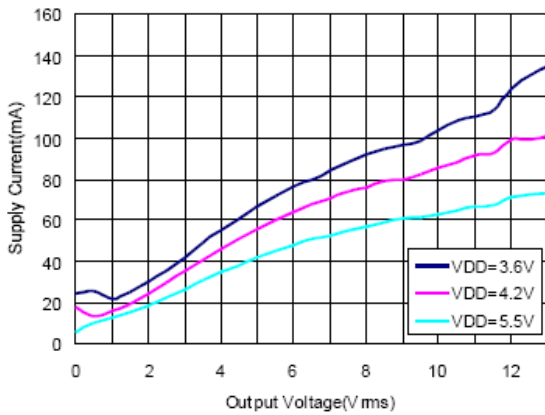
Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, $V_{DD} = 3.6\text{V}$, $C_L = 1\mu\text{F}$, V_{SET} Float, unless otherwise specified.)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units |
|---------------------------------------|------------|---|----------------|------|--------------|-------|
| Input Voltage | V_{DD} | | 2.5 | | 5.5 | V |
| Quiescent Current | I_Q | EN > 1.2V, $V_{SET} = \text{High}$ | | 30 | 48 | mA |
| | | EN > 1.2V, $V_{SET} = \text{Floating}$ | | 10 | 18 | |
| | | EN > 1.2V, $V_{SET} = \text{GND}$ | | 5 | 12 | |
| Shutdown Current | I_{SD} | EN = 0V | | 0.1 | 1 | μA |
| Wake-Up Time | T_{WU} | EN from Low to High | | 40 | | mS |
| Chip Enable | V_{EH} | | 1.2 | | | V |
| Chip Disable | V_{EL} | | | | 0.4 | |
| GSET/ VSET High | V_H | | $V_{DD} - 0.5$ | | V_{DD} | V |
| GSET/ VSET Floating | V_F | | 1 | | $V_{DD} - 1$ | |
| GSET/ VSET Low | V_L | | 0 | | 0.5 | |
| Under Voltage Lockout Threshold | UVLO | VDD from High to Low | | 2.2 | | V |
| Under Voltage Lockout Hysteresis | UVLO(H) | VDD from Low to High | | 0.2 | | |
| Thermal Shutdown Threshold | OTP | | | 150 | | °C |
| Thermal Shutdown Lockout Hysteresis | OTP(H) | | | 30 | | °C |
| Boost Converter | | | | | | |
| Output Voltage | V_{O1} | $V_{SET} = \text{GND}$, No Load | 7.2 | 8 | 8.8 | V |
| | V_{O2} | $V_{SET} = \text{NC}$, No Load | 10.8 | 12 | 13.2 | V |
| | V_{O3} | $V_{SET} = \text{AVDD}$, No Load | 16 | 17.5 | 19 | V |
| Current Limit | C_L | Average Input Current | | 0.8 | | A |
| Lowside MOSFET $R_{DS(ON)}$ | R_{LS} | $I_O = 50\text{mA}$ | | 0.5 | | Ω |
| Boost Switching Frequency | f_{OSCB} | | 1.1 | 1.5 | 1.9 | MHz |
| Class D | | | | | | |
| Class D Amplifier Switching Frequency | f_{OSCD} | Input AC-GND | 225 | 375 | 475 | KHz |
| Common Mode Reject Ratio | CMRR | $V_{IN} = + -100\text{mV}$, $V_{DD} = 3.6\text{V}$ | | 60 | | dB |
| Output Offset Voltage | V_{OS} | Output Offset Voltage | | 5 | 50 | mV |
| $R_{DS(ON)}$ | RP | High Side | | 1.5 | | Ω |
| | | Low Side | | 0.6 | | Ω |
| Closed-Loop Voltage Gain | A_{V1} | $G_{SET} = \text{AVDD}$, $V_O = 1V_{RMS}$ | 25 | 26 | 27 | |
| | A_{V2} | $G_{SET} = \text{NC}$, $V_O = 1V_{RMS}$ | 21 | 22 | 23 | |
| | A_{V3} | $G_{SET} = \text{GND}$, $V_O = 1V_{RMS}$ | 17 | 18 | 19 | dB |
| Power Supply Reject Ratio | PSRR | 200m V_{PP} Supply Ripple @ 217Hz | | 70 | | dB |
| Total Harmonic Distortion Plus Noise | THD+N | $V_O = 5V_{RMS}$ | | 0.3 | | % |
| Signal to Noise Ratio | SNR | Input AC Ground, A-Weighting | | 90 | | dB |

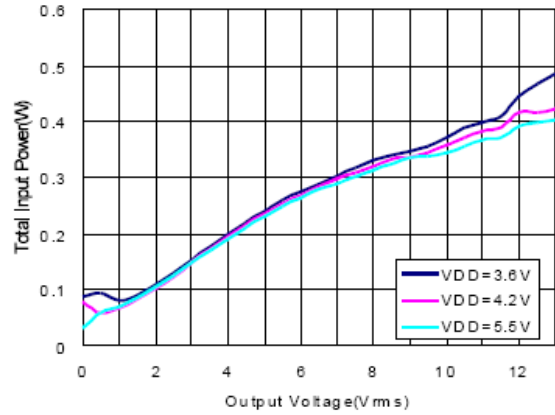
Typical Performance Characteristics

(@T_A = +25°C, V_{DD} = 4.2V, Gain = 26dB, C_{IN} = 1μF, C_{LOAD} = 1μF, unless otherwise specified.)

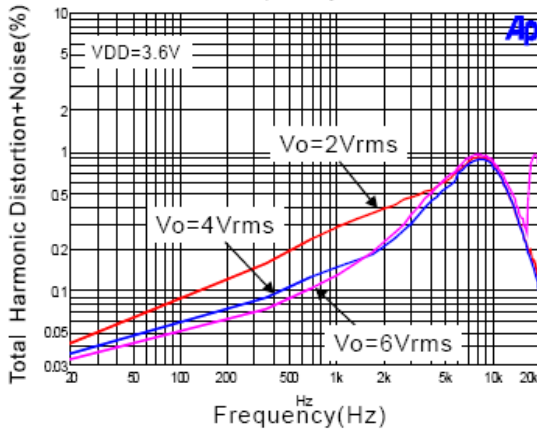
1. Total Supply Current VS Output Voltage



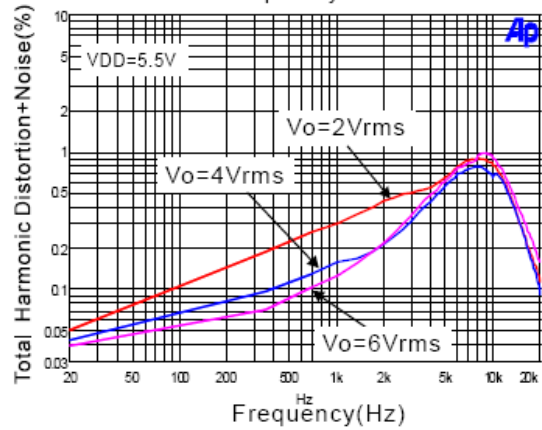
2. Total Input Power VS Output Voltage



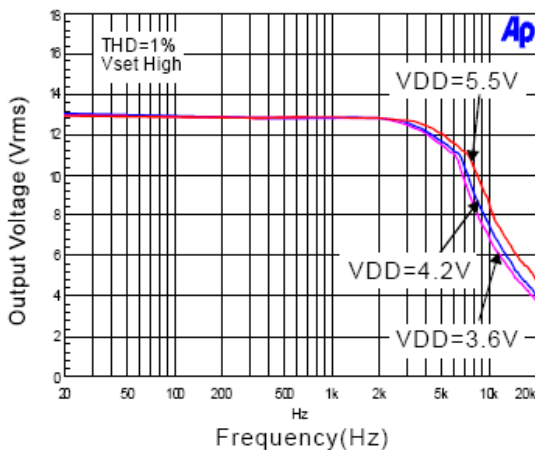
3. THD+N VS Frequency



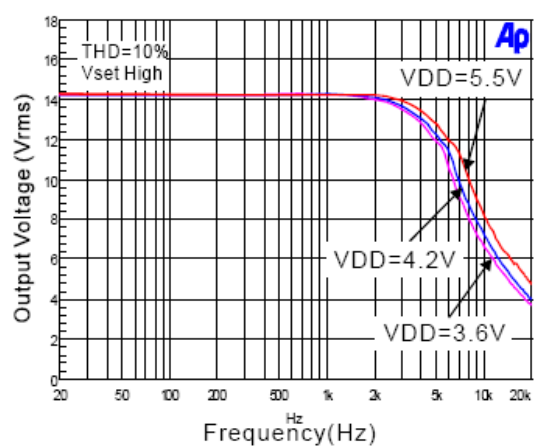
4. THD+N VS Frequency



5. Output Voltage RMS VS Frequency

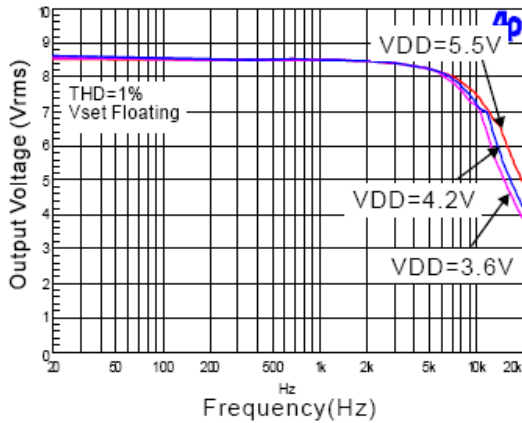


6. Output Voltage RMS VS Frequency

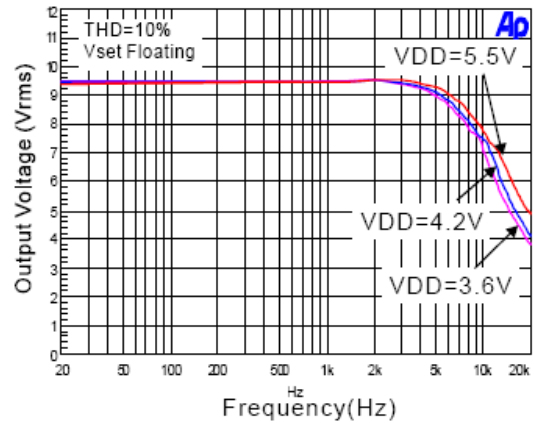


Typical Performance Characteristics (cont.) (@T_A = +25°C, V_{DD} = 5V, Gain = 18dB, unless otherwise specified.)

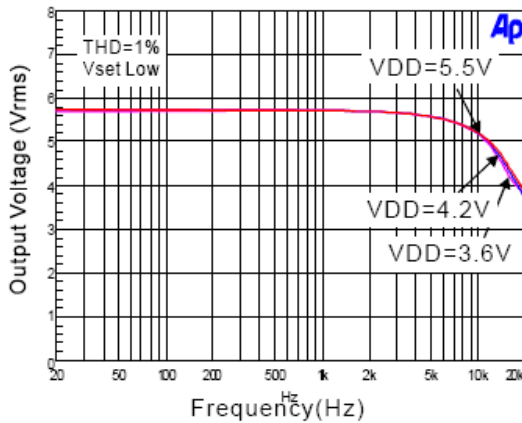
7. Output Voltage RMS VS Frequency



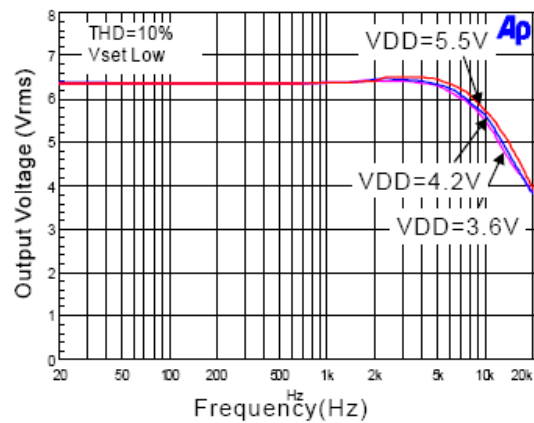
8. Output Voltage RMS VS Frequency



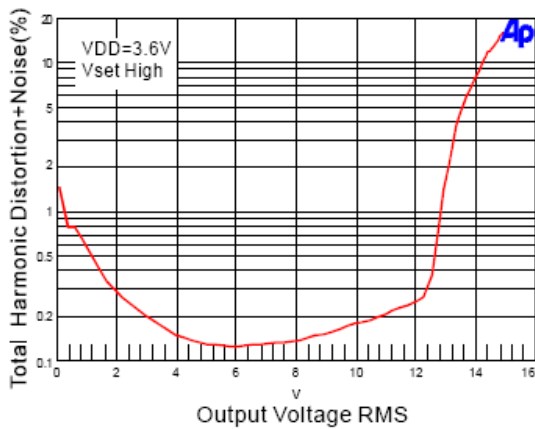
9. Output Voltage RMS VS Frequency



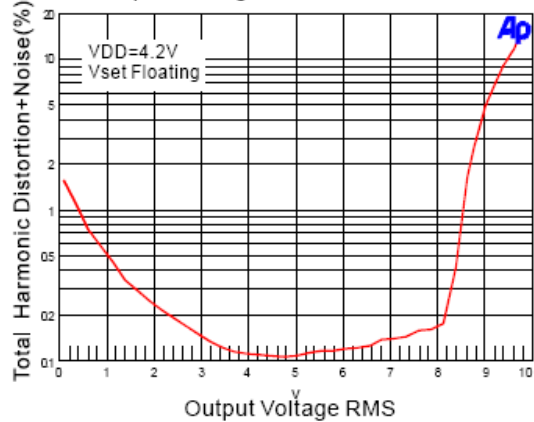
10. Output Voltage RMS VS Frequency



11. Output Voltage RMS VS THD+N



12. Output Voltage RMS VS THD+N



Application Information

Select Boost Converter Output Voltage

Customer can use V_{SET} pin to set boost converter output voltage between 8V, 12V and 17.5V. V_{SET} pin configuration table as below:

| V _{SET} Pin Configuration | Min | Max | PVCC Voltage | Audio Amplifier Maximum Output Voltage |
|------------------------------------|------------|-----------|--------------|---|
| Connect to AVDD | AVDD – 0.5 | AVDD | 17.5V | 11 V _{RMS} (V _{PP} = 31.1V) |
| Floating | 1V | AVDD – 1V | 12V | 8 V _{RMS} (V _{PP} = 22.6V) |
| Connect to GND | GND | 0.5V | 8V | 5 V _{RMS} (V _{PP} = 14.1V) |

Input Resistance (R_i)

The input resistors (R_i = R_{IN} + R_{EX}) set the gain of the amplifier according to Equation 1 when anti-saturation is inactive.

$$G = 20 \text{ Log } [12.8 * R_F / (R_{IN} + R_{EX})] \text{ (dB)}$$

| G _{SET} | R _{IN} | R _{FB} |
|------------------------------------|-----------------|-----------------|
| G _{SET} = V _{DD} | 77.4kΩ | 122.6kΩ |
| G _{SET} = Floating | 100kΩ | 100kΩ |
| G _{SET} = GND | 122.6kΩ | 77.4kΩ |

Where R_{IN} is a 77.4KΩ internal resistor, R_{EX} is the external input resistor, R_F is a 122.6KΩ internal resistor. Resistor matching is very important in fully differential amplifiers. The balance of the output on the reference voltage depends on matched ratios of the resistors. CMRR, PSRR, and cancellation of the second harmonic distortion diminish if resistor mismatch occurs. Therefore, it is recommended to use 1% tolerance resistors or better to keep the performance optimized. Matching is more important than overall tolerance. Resistor arrays with 1% matching can be used with a tolerance greater than 1%. Place the input resistors very close to the PAM8902 to limit noise injection on the high-impedance nodes. For optimal performance the gain should be set to lower. Lower gain allows the PAM8902 to operate at its best, and keeps a high voltage at the input making the inputs less susceptible to noise. In addition to these features, higher value of R_i minimizes pop noise.

Input Capacitors (C_i)

In the typical application, an input capacitor, C_i, is required to allow the amplifier to bias the input signal to the proper DC level for optimum operation. In this case, C_i and the minimum input impedance R_i form is a high-pass filter with the corner frequency determined in the follow equation:

$$F_C = \frac{1}{2\pi R_i C_i}$$

It is important to consider the value of C_i as it directly affects the low frequency performance of the circuit.

For example, when R_i is 150k and the specification calls for a flat bass response are down to 150Hz.

Equation is reconfigured as followed:

$$C_i = \frac{1}{2\pi R_i F_C}$$

When input resistance variation is considered, the C_i is 7nF, so one would likely choose a value of 10nF. A further consideration for this capacitor is the leakage path from the input source through the input network (C_i, R_i + R_F) to the load. This leakage current creates a DC offset voltage at the input to the amplifier that reduces useful headroom, especially in high gain applications. For this reason, a low-leakage tantalum or ceramic capacitor is the best choice. When polarized capacitors are used, the positive side of the capacitor should face the amplifier input in most applications as the DC level is held at V_{DD} /2, which is likely higher than the source DC level. Please note that it is important to confirm the capacitor polarity in the application.

Application Information

Decoupling Capacitor

The PAM8902 is a high-performance CMOS audio amplifier that requires adequate power supply decoupling to ensure the output total harmonic distortion (THD) as low as possible. The optimum decoupling is achieved by using two different types of capacitors that target on different types of noise on the power supply leads. For higher frequency transients, spikes, or digital hash on the line, a good low equivalent series-resistance (ESR) ceramic capacitor, typically 1 μ F is placed as close as possible to the device AVDD pin for the best operation. For filtering lower frequency noise signals, a large ceramic capacitor of 10 μ F or greater placed near the AVDD supply trace is recommended.

External Schottky Diode

Use external schottky diode can get the best driving capability and efficiency.

Since internal power diode has limited driving capability, only in following conditions customer can remove the external schottky diode to reduce the cost.

1. VSET = GND or Floating and C_L less than 1 μ F.
2. The signal frequency less than 4KHz.
3. Haptic application (50-500Hz)

Shutdown Operation

In order to reduce power consumption while not in use, the PAM8902 contains shutdown circuitry amplifier off when a logic low is placed on the ENA pin. By switching the ENA pin connected to GND, the PAM8902 supply current draw will be minimized in idle mode.

Under-Voltage Lock-Out (UVLO)

The PAM8902 incorporates circuitry designed to detect supply voltage. When the supply voltage drops to 2.2V or below, the PAM8902 goes into a state of shutdown, and the device comes out of its shutdown state and restore to normal function only when reset the power supply or ENA pin.

Short-Circuit Protection (SCP)

The PAM8902 has short circuit protection circuitry on the outputs to prevent the device from damage when output-to-output shorted or output-to-GND shorted occurs. When a short circuit occurs, the device goes into a latch state and must be reset by cycling the voltage on the ENA pin to a logic low and then back to the logic high state for normal operation. This will clear the short-circuit flag and allow for normal operation if the short was removed. If the short was not removed, the protection circuitry will again activate.

Over-Temperature Protection (OTP)

Thermal protection on the PAM8902 prevents the device from damage when the internal die temperature exceeds +150°C. There is a +15°C tolerance on this trip point from device to device. Once the die temperature exceeds the set point, the device will enter the shutdown state and the outputs are disabled in this condition both OUT+ and OUT- will become high impedance. This is not a latched fault. The thermal fault is cleared once the temperature of the die decreased by +30°C. This large hysteresis will prevent motor boating sound well and the device begins normal operation at this point with no external system interaction.

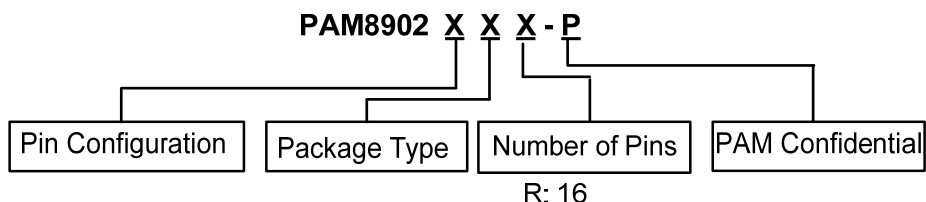


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PAM8902

Ordering Information



| Part Number | Part Marking | Package Type | Standard Package |
|--------------|----------------|--------------|---------------------|
| PAM8902ZER-P | BG YW | CSP-16L | 3000Units/Tape&Reel |
| PAM8902KER-P | P8902 XXXYW | QFN4x4-16L | 3000Units/Tape&Reel |

Marking Information

Y: Last Digital of Manufacturing Year

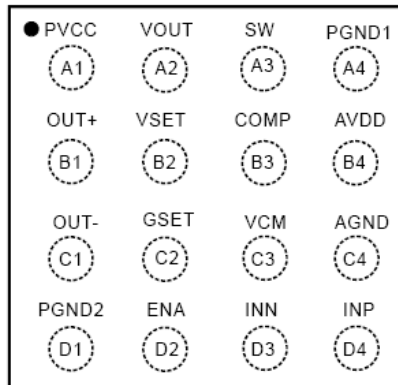
6: 2006
7: 2007
8: 2008
9: 2009
0: 2010
1: 2011

W: Week Code

| Item | Week Code | Item | Week Code | Item | Week Code | Item | Week Code |
|------|-----------|------|-----------|------|-----------|------|-----------|
| 1 | A | 14 | N | 27 | <u>A</u> | 40 | <u>N</u> |
| 2 | B | 15 | O | 28 | <u>B</u> | 41 | <u>O</u> |
| 3 | C | 16 | P | 29 | <u>C</u> | 42 | <u>P</u> |
| 4 | D | 17 | Q | 30 | <u>D</u> | 43 | <u>Q</u> |
| 5 | E | 18 | R | 31 | <u>E</u> | 44 | <u>R</u> |
| 6 | F | 19 | S | 32 | <u>F</u> | 45 | <u>S</u> |
| 7 | G | 20 | T | 33 | <u>G</u> | 46 | <u>T</u> |
| 8 | H | 21 | U | 34 | <u>H</u> | 47 | <u>U</u> |
| 9 | I | 22 | V | 35 | <u>I</u> | 48 | <u>V</u> |
| 10 | J | 23 | W | 36 | <u>J</u> | 49 | <u>W</u> |
| 11 | K | 24 | X | 37 | <u>K</u> | 50 | <u>X</u> |
| 12 | L | 25 | Y | 38 | <u>L</u> | 51 | <u>Y</u> |
| 13 | M | 26 | Z | 39 | <u>M</u> | 52 | <u>Z</u> |

Marking Information (cont.)

16 Ball CSP
Top View



Marking

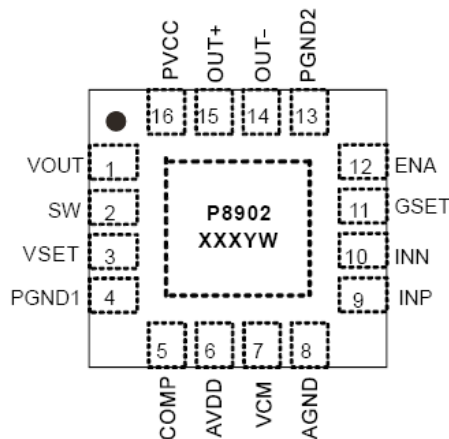
BG
YW

BG: Product Code of PAM8902

Y: Year

W: Week

Top View
QFN 4X4 16L



Y: Year

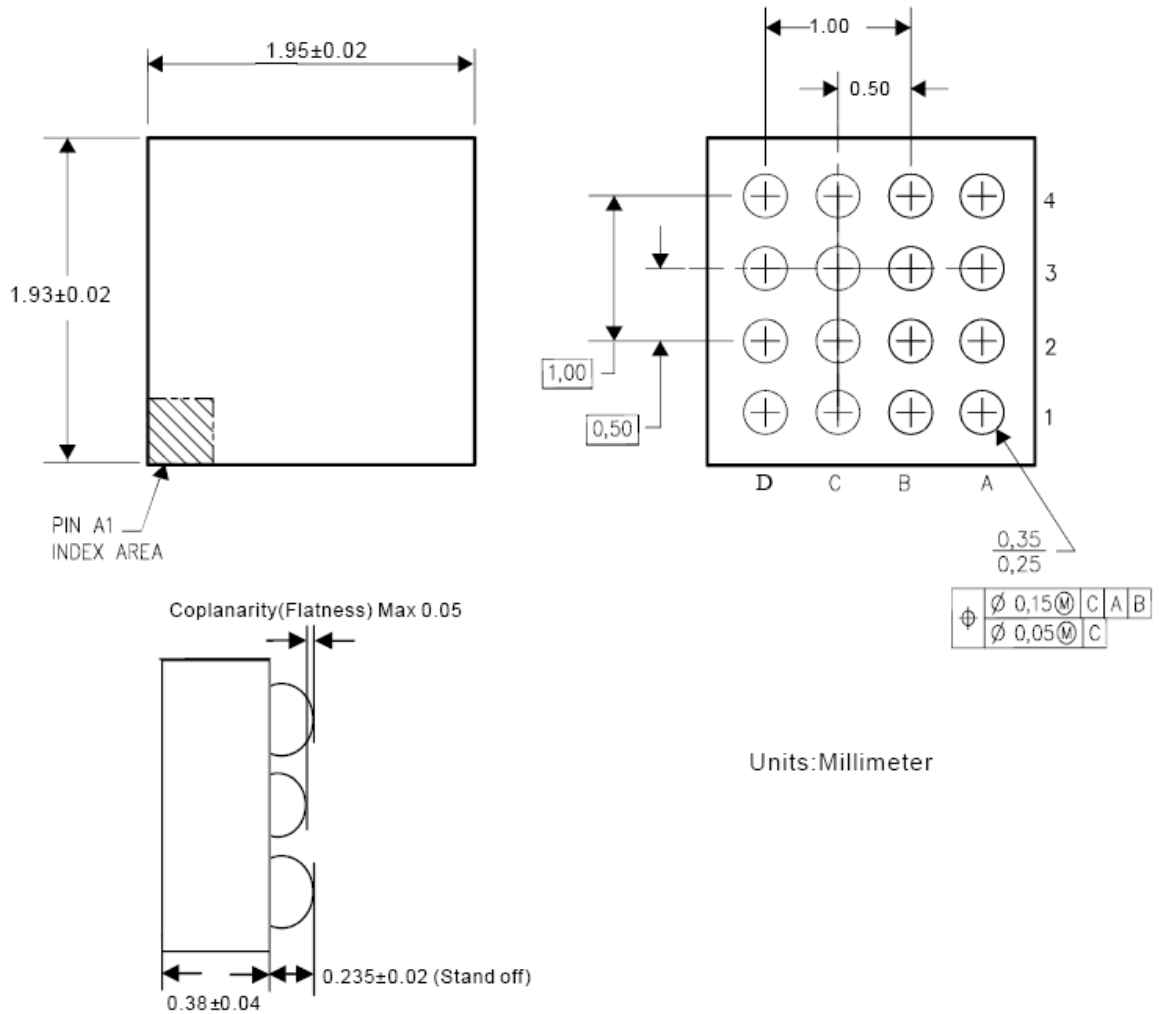
W: Week

X: Internal Code

●: Pin 1 Indicator

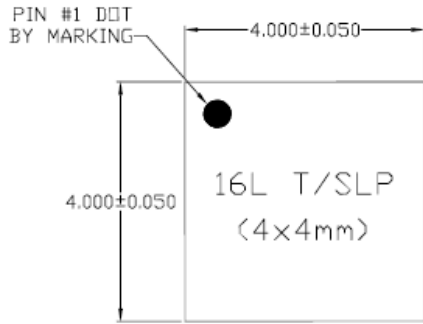
Package Outline Dimensions (All dimensions in mm.)

CSP-16

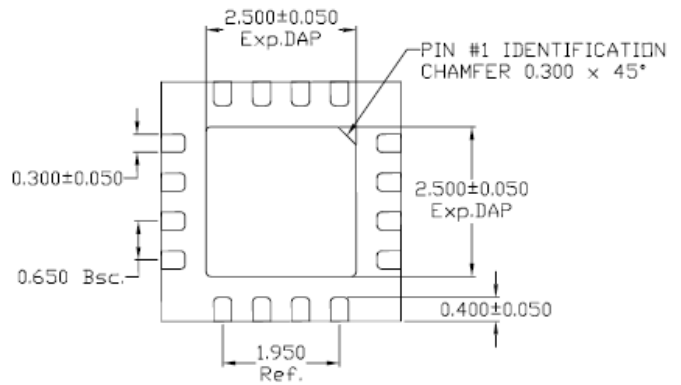


Package Outline Dimensions (cont.) (All dimensions in mm.)

QFN4x4-16



TOP VIEW

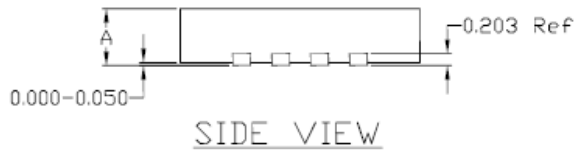


BOTTOM VIEW

NOTE:

1) TSLP AND SLP SHARE THE SAME EXPOSE OUTLINE BUT WITH DIFFERENT THICKNESS:

| | | TSLP | SLP |
|---|------|-------|-------|
| A | MAX. | 0.800 | 0.900 |
| | NOM. | 0.750 | 0.850 |
| | MIN. | 0.700 | 0.800 |



SIDE VIEW

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Diodes Incorporated****PAM8902****IMPORTANT NOTICE**

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B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

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